WE CLAIM:

- 1. An oscillator, comprising:
- a first phase shift circuit including a first pole;

a second phase shift circuit including a second pole, and having an input coupled to an output of said first phase shift circuit; and

a third phase shift circuit including a third pole, and having an input coupled to an output of said second phase shift circuit, wherein an output of said third phase shift circuit is cross-coupled to an input of said first phase shift circuit,

wherein at least one of said first, second and third poles includes a varactor to generate a phase shift according to said at least one of said first, second and third poles.

- 2. The oscillator of claim 1, wherein said at least one of said first, second or third poles generates said phase shift, said phase shift comprising approximately 1/3 of a cross-coupled phase shift.
- 3. The oscillator of claim 1, wherein the varactor comprises an n-channel metal oxide semiconductor.
- 4. The oscillator of claim 3, wherein the varactor comprises the n-channel metal oxide semiconductor in an Nwell configuration.

- 5. The oscillator of claim 1, wherein the varactor comprises a capacitance to the at least one of said first, second or third poles.
- 6. The oscillator of claim 5, wherein the capacitance allows a frequency to be tuned.
- 7. A ring oscillator having three stages, the ring oscillator comprising:

a phase shift circuit to tune a frequency of an output signal; and a pole within the phase shift circuit, wherein the pole includes a varactor to provide a capacitance for the pole.

- 8. The ring oscillator of claim 7, further comprising a first stage and a final stage, wherein an output of the final stage is cross-coupled to an input of the first stage.
- 9. The ring oscillator of claim 8, wherein the final stage comprises the phase shift circuit.
- 10. The ring oscillator of claim 7, wherein the pole comprises a resistance.
 - 11. The ring oscillator of claim 1, wherein the varactor comprises

an n-channel metal oxide semiconductor.

- 12. The ring oscillator of claim 11, wherein the varactor comprises the n-channel metal oxide semiconductor in an Nwell configuration.
 - 13. A circuit for providing a signal, the circuit comprising: a voltage supply;

an oscillator including at least two phase shift circuits, wherein a final phase shift circuit is a cross-coupled to a first phase shift circuit;

a diode coupled to the voltage supply and the final phase shift circuit of the at least two phase shift circuits; and

a varactor within a pole of the final phase shift circuit, wherein the varactor tunes a frequency of a signal generated by the oscillator.

- 14. The circuit of claim 13, wherein the varactor comprises an n-channel metal oxide semiconductor.
- 15. The circuit of claim 14, wherein the varactor comprises the nchannel metal oxide semiconductor in a Nwell configuration.
- 16. A method for generating an output signal in a ring oscillator, the method comprising:

applying a voltage control signal to a pole within a phase shift

circuit;

generating on output signal having a frequency according to the pole; and

generating a phase shift in the phase shift circuit according to the pole.

- 17. The method of claim 16, further comprising receiving the voltage control signal at the phase shift circuit.
- 18. The method of claim 16, further comprising using a feedback signal to determine the frequency of the output signal.
- 19. The method of claim 18, further comprising adjusting the pole according to feedback signal.
- 20. The method of claim 16, further comprising applying the voltage control signal to another phase shift circuit.
- 21. The method of claim 20, wherein the applying step comprises applying the voltage control signal to another pole in another phase shift circuit.
 - 22. A circuit for generating an output signal, the circuit comprising:

applying means for applying a voltage control signal to a pole within a phase shift circuit;

first generating means for generating an output signal having a frequency according to the pole; and

second generating means for generating a phase shift in the phase shift circuit according to the pole.